## **High Power LED Series**

# LH502C General



High efficacy and lumen makes

The LH502C suitable for Streetlight and High-bay applications

## **Features & Benefits**

- Operates at a maximum current of up to 880mA
- Uniform light distribution under any beam angle
- Strengthened Anti sulfurization
- Color binning @ 85°C









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## 1. Characteristics

## a) Absolute Maximum Rating

ltem	Symbol	Rating	Unit	Condition
Operating Temperature	$T_{opr}$	-40 ~ +85	°C	
Storage Temperature	$T_{stg}$	-40 ~ +100	°C	-
LED Junction Temperature	T <sub>j</sub>	125	°C	-
Forward Current	I <sub>F</sub>	880	mA	-
Peak Pulse Forward Current	I <sub>FP</sub>	1000	mA	Duty cycle≤1/10, pulse width 10ms
Soldering Temperature		260 <10	°C	-

## b) Electro-optical Characteristics ( $I_{\textrm{F}}$ = 640 mA, $T_{\textrm{j}}$ = 25°C $\,$ )

ltem	Unit	Rank	Min.	Тур.	Max.
Forward Voltage (V <sub>F</sub> )	V	YE	5.9	6.1	6.3
		3	70	-	-
Color Rendering Index (R <sub>a</sub> )	-	5	80		
		7	90	-	-
Thermal Resistance (junction to chip point)	°C/W		-	3	-
Beam Angle	0		-	120	-
ESD (HBM)	-			Class 3A	

## Notes:

Samsung maintains measurement tolerance of: luminous flux =  $\pm 7$  %, forward voltage =  $\pm 0.1$  V



## c) Luminous Flux Characteristics (I<sub>F</sub> = 640 mA)

CRI (R₃)	Nominal	Flux		Flux @ T <sub>J</sub> = 25 °C (lm)	
Min.	CCT (K)	Rank	Min.	Тур.	Max.
	2200K	A2	510		
	2700K	A2	590		
	3000K	A2	620		
70	3500K	A2	640		
70	4000K	A2	660		
	5000K	A2	660		
	5700K	A2	640		
	6500K	A2	630		
	2200K	A2	440		
	2700K	A2	530		
	3000K	A2	550		
80	3500K	A2	580		
80	4000K	A2	600		
	5000K	A2	600		
	5700K	A2	590		
	6500K	A2	590		
	2200K	A2	400		
	2700K	A2	450		
	3000K	A2	470		
90	3500K	A2	480		
	4000K	A2	490		
	5000K	A2	490		
	5700K	A2	490		

## Notes:

- 1) Tested in pulsed operating condition at rated test current (10 ms pulse width) and rated temperature
- 2) Samsung maintains measurement tolerance of: Luminous flux =  $\pm 7$  %, CRI =  $\pm 1$

## 2. Product Code Information

1	2	3	4	5	6	7	8	9	10	11	12	13	14	15	16	17	18
	_								_	_			_		_		_

Digit	PKG Information	Code			Specification				
1 2 3	Samsung Package High Power	SPH	High Power PKG						
4 5	Color	WH	White `	White `					
6	Product Version	1	1						
7 8	Form Factor	L5	5050 size						
9	Lens Type	N	No lens						
10	Model	6	5050 Series	5050 Series					
11	Internal Code	0							
		3	Min. 70						
12	CRI	5	Min. 80						
		7	Min. 90						
13 14	Forward Voltage (V)	YE	Bin code	Α0	5.9 – 6.1				
13 14	Torward voitage (v)	"-	Dill code	A1	6.1 – 6.3				
		Υ	2200K						
		W	2700K						
		V	3000K						
15	CCT (K)	U	3500K						
15	CCT (K)	Т	4000K						
		R	5000K						
		Q	5700K						
		P	6500K (CRI70/80	))					
16	MacAdam Step	3	MacAdam 3-Ste	0					
10	iviacAuaiii Step	5	MacAdam 5-Ste	o					
17 18	Luminous Flux (lm)	A2							

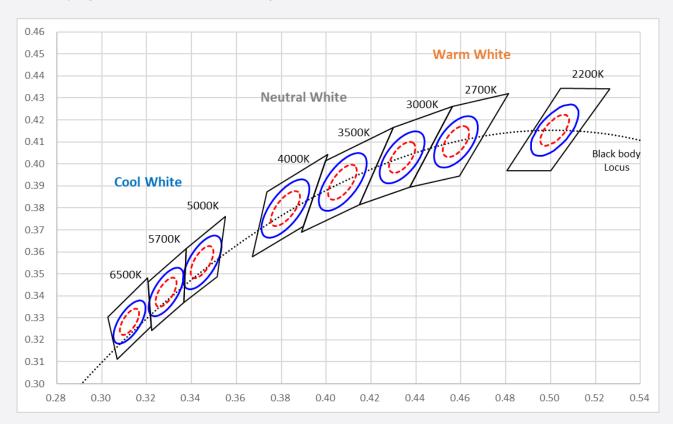
## a) Luminous flux Rank ( $I_F = 640$ mA, $T_j = 25$ °C )

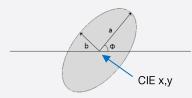
CRI (Ra)	Nominal	David and d	\/F.D	Chrom	Flo	ıx	Flux Range
Min.	CCT(K)	Product Code	VF Rank	Rank (Bins)	Rank	Bins	(Φv, lm)
	2200	SPHWH1L5N603YEY3A2				51	510-550
	2200	SPHWH1L5N603YEY5A2		Y3, Y5		55	550-590
		SPHWH1L5N603YEW3A2				59	590-630
	2700	SPHWH1L5N603YEW5A2		W3, W5		63	630-670
70		SPHWH1L5N603YEV3A2				62	620-660
	3000	SPHWH1L5N603YEV5A2		V3, V5		66	660-700
		SPHWH1L5N603YEU3A2				64	640-680
	3500	SPHWH1L5N603YEU5A2		U3, U5		68	680-720
70		SPHWH1L5N603YET3A2	YE		A2	66	660-700
	4000	SPHWH1L5N603YET5A2		T3, T5		70	700-740
		SPHWH1L5N603YER3A2				66	660-700
	5000	SPHWH1L5N603YER5A2		R3, R5		70	700-740
		SPHWH1L5N603YEQ3A2				64	640-680
	5700	SPHWH1L5N603YEQ5A2		Q3, Q5		68	680-720
		SPHWH1L5N603YEP3A2				63	630-670
	6500	SPHWH1L5N603YEP5A2		P3, P5		67	670-710
		SPHWH1L5N605YEY3A2				44	440-480
	2200	SPHWH1L5N605YEY5A2		Y3, Y5		48	480-520
2700		SPHWH1L5N605YEW3A2		W/2 14/5		53	530-570
	2700	SPHWH1L5N605YEW5A2		W3, W5		57	570-610
80		SPHWH1L5N605YEV3A2		V2 V5		55	550-590
	3000	SPHWH1L5N605YEV5A2		V3, V5		59	590-630
		SPHWH1L5N605YEU3A2				58	580-620
	3500	SPHWH1L5N605YEU5A2		U3, U5		62	620-660
	4000	SPHWH1L5N605YET3A2	YE		A2	60	600-640
	4000	SPHWH1L5N605YET5A2		T3, T5		64	640-680
		SPHWH1L5N605YER3A2				60	600-640
	5000	SPHWH1L5N605YER5A2		R3, R5		64	640-680
		SPHWH1L5N605YEQ3A2	***			59	590-630
	5700	SPHWH1L5N605YEQ5A2		Q3, Q5		63	630-670
		SPHWH1L5N605YEP3A2				59	590-630
	6500	SPHWH1L5N605YEP5A2		P3, P5		63	630-670
		SPHWH1L5N607YEY3A2				40	400-440
	2200	SPHWH1L5N607YEY5A2		Y3, Y5		44	440-480
		SPHWH1L5N607YEW3A2				45	450-490
	2700	SPHWH1L5N607YEW5A2		W3, W5		49	490-530
		SPHWH1L5N607YEV3A2				47	470-510
	3000	SPHWH1L5N607YEV5A2		V3, V5		51	510-550
		SPHWH1L5N607YEU3A2				48	480-520
90	3500	SPHWH1L5N607YEU5A2	YE	U3, U5	A2	52	520-560
		SPHWH1L5N607YET3A2				49	490-530
	4000	SPHWH1L5N607YET5A2		T3, T5		53	530-570
		SPHWH1L5N607YER3A2				49	490-530
	5000	SPHWH1L5N607YER5A2		R3, R5		53	530-570
		SPHWH1L5N607YEQ3A2				49	490-530
	5700	SPHWH1L5N607YEQ5A2		Q3, Q5		53	530-570

## b) Voltage Bins $(I_F = 640 \text{ mA}, T_j = 25^{\circ}\text{C})$

Nominal CCT (K)	CRI (R <sub>a</sub> ) Min.	Product Code	Voltage Rank	Voltage Bin	Voltage Range (V)
			VE	Α0	5.9 - 6.1
-	•		YE	A1	6.1 - 6.3

## c) Chromaticity Region & Coordinates ( $I_F = 640$ mA, $T_j = 85$ °C )





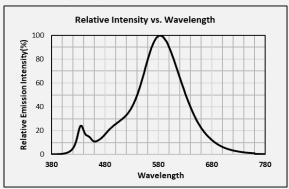
CRI	ССТ	Rank	CIE x	CIE y	Ф	А	b
	2200K	Y3	0.5019	0.4153	40.2	0.0086	0.0040
	2200K	<b>Y</b> 5	0.3019	0.4153	49.3	0.0144	0.0066
	2700K	W3	0.4578	0.4101	53.7	0.0081	0.0042
	2700K	W5	0.4378	0.4101	33.7	0.0135	0.0070
	3000K	V3	0.4338	0.4030	53.2	0.0083	0.0041
	3000K	V5	0.4336	0.4030	33.2	0.0138	0.0068
	3500К	U3	0.4073	0.3917	54.0	0.0093	0.0041
70 80		U5	0.4073	0.3917	34.0	0.0155	0.0069
90	4000K	Т3	0.3818	0.3797	53.7	0.0094	0.0040
	40001	T5	0.3818	0.3757	33.7	0.0157	0.0067
	5000K	R3	0.3447	0.2552	59.6	0.0082	0.0035
	3000K	R5	0.3447	0.3553	39.0	0.0137	0.0058
	5700K	Q3	0.3287	0.3417	59.1	0.0075	0.0032
	3700K	Q5	0.3287	0.3417	33.1	0.0125	0.0053
	SEOOK .	Р3	0.3123	0.3282	58.6	0.0067	0.0029
	6500K	P5	0.5123	0.3282	50.0	0.0112	0.0048

**Note :** Samsung maintains measurement tolerance of: Cx,  $Cy = \pm 0.005$ 

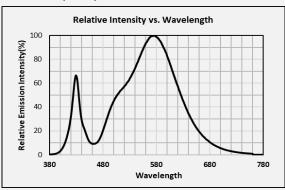
## 3. Typical Characteristic Graphs

## a) Spectral Distribution ( $I_F = 640 \text{ mA}$ , $T_j = 25^{\circ}\text{C}$ )

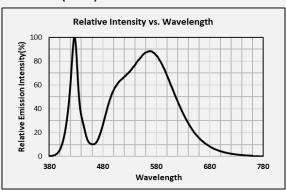
## CCT: 2200K (CRI70)



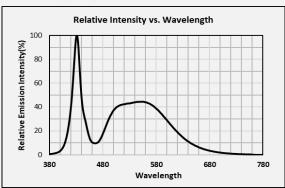
## CCT:3000K (CRI70)



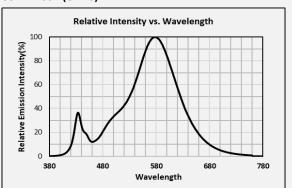
CCT:4000K (CRI70)



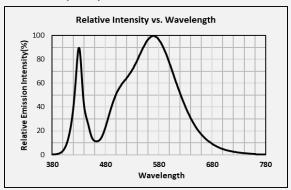
CCT:5700K (CRI70)



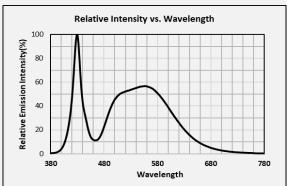
## CCT: 2700K (CRI70)



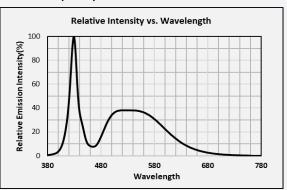
CCT: 3500K (CRI70)



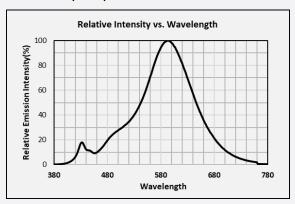
CCT: 5000K (CRI70)



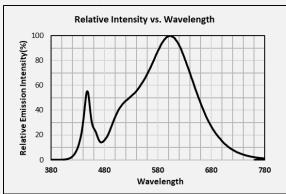
CCT: 6500K (CRI70)



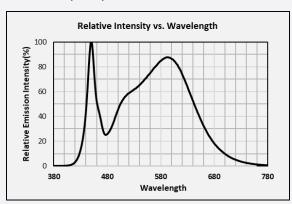
## CCT: 2200K (CRI80)



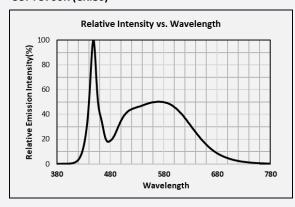
CCT: 3000K (CRI80)



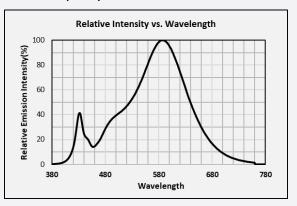
CCT: 4000K (CRI80)



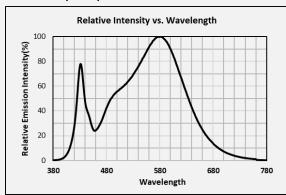
CCT: 5700K (CRI80)



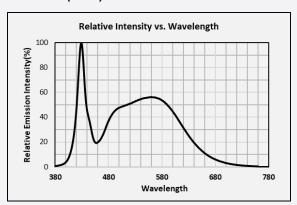
## CCT: 2700K (CRI80)



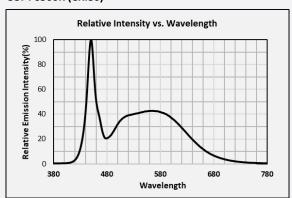
CCT: 3500K (CRI80)



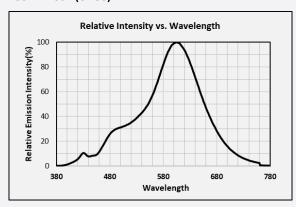
CCT: 5000K (CRI80)



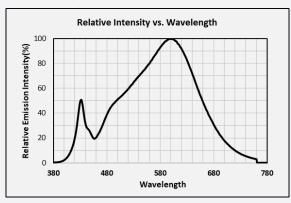
CCT: 6500K (CRI80)



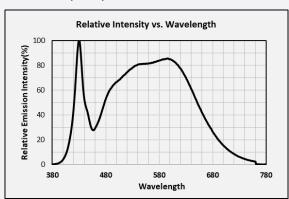
## CCT: 2200K (CRI90)



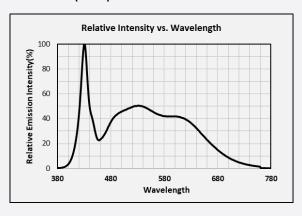
CCT: 3000K (CRI90)



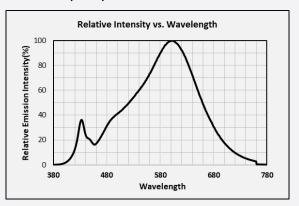
CCT: 4000K (CRI90)



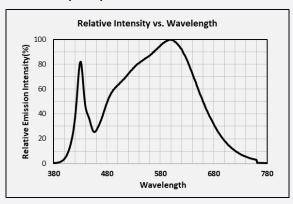
CCT: 5700K (CRI90)



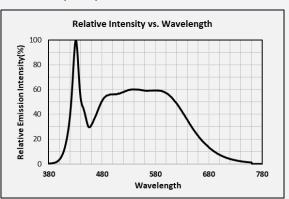
## CCT: 2700K (CRI90)



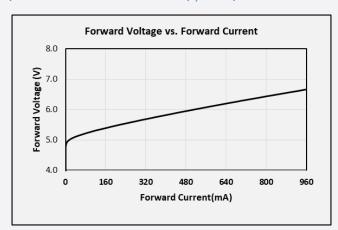
CCT: 3500K (CRI90)

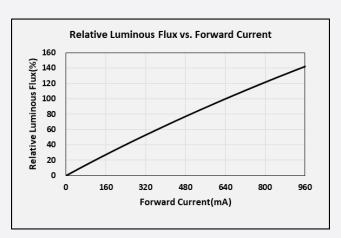


CCT: 5000K (CRI90)

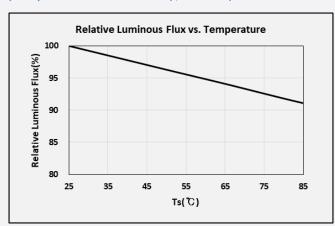


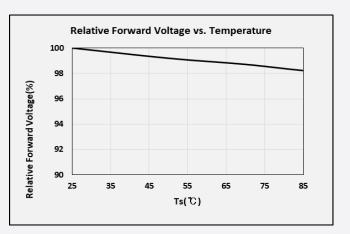
## b) Forward Current Characteristics $(T_{ij} = 25^{\circ}C)$



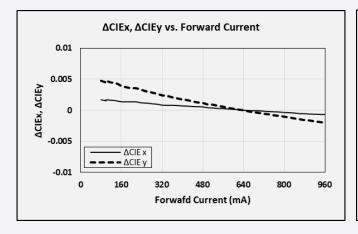


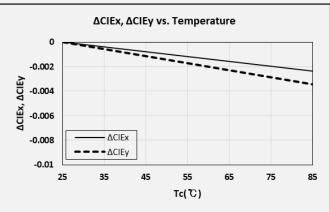
### c) Temperature Characteristics (I<sub>F</sub> = 640 mA)



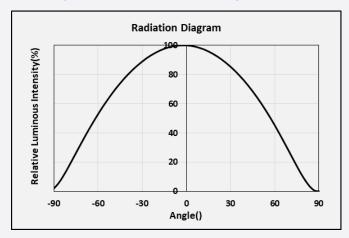


## d) Color Shift Characteristics (I<sub>F</sub> = 640 mA, $T_j$ = 25°C)



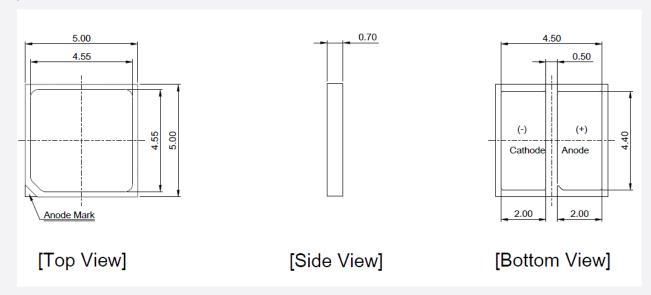


## e) Beam Angle Characteristics (I<sub>F</sub> = 640 mA, $T_j$ = 25°C)



## 4. Outline Drawing & Dimension

## a) Mechanical Dimensions



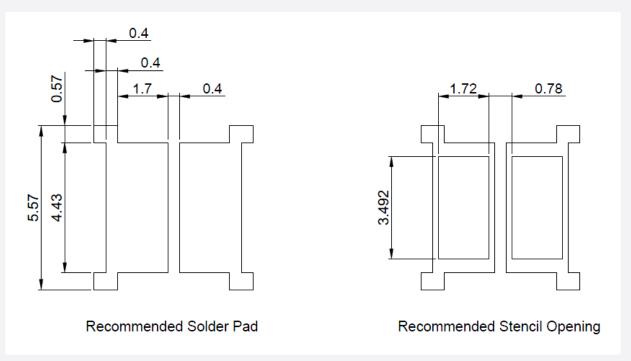
## Notes:

1) Mark for the Anode

2) Unit: mm

3) Tolerance: ±0.1mm

## b) Recommended Solder Pad



## 5. Reliability Test Items & Conditions

## a) Test Items

Test Item	Test Condition	Test Hour / Cycle
High Temperature Operating Life Test	85℃, 440mA	1000 h
Wet High Temperature Operating Life Test	85℃, 85 % RH, DC 440mA	1000 h
Temperature Cycling	-45°C / 15min ~ 125°C / 15min Temperature change within 5min	500 cycles
ESD (HBM)	R1: 10 MΩ R2: 1.5 kΩ C: 100 pF V: ±8 kV	5 times
Vibration Test	20~ 80 Hz (displacement: 0.06 inch, max. 20 g) 80 ~ 2 kHz (max. 20 g) min. frequency ↔max. frequency 4 min transfer	4 times
Mechanical Shock Test	1500g, 0.5 ms each of the 6 surfaces (3 axis x 2 sides)	5 times

## b) Criteria for Judging the Damage

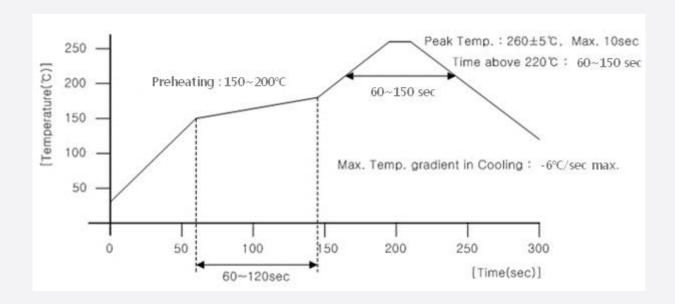
Item	Symbol	Test Condition	Lin	Limit			
item	Зушиот	(T <sub>c</sub> = 25°C)	Min.	Max.			
Forward Voltage	$V_{\text{F}}$	I <sub>F</sub> = Sorting Current	L.S.L. * 0.9	U.S.L. * 1.1			
Luminous Flux	Фи	I <sub>F</sub> = Sorting Current	L.S.L * 0.7	U.S.L * 1.3			



## **6. Soldering Conditions**

## a) Reflow Conditions (Pb free)

Reflow frequency: 2 times max.



## b) Manual Soldering Conditions

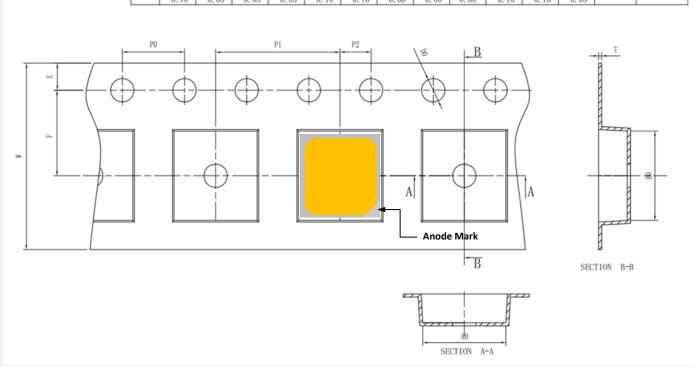
Not more than 5 seconds @ max. 300°C, under soldering iron.

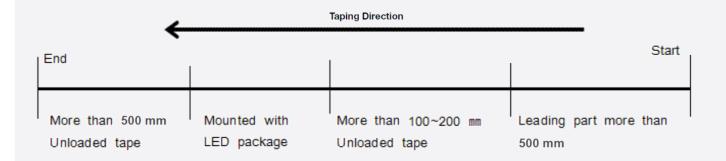
## 7. Tape & Reel

## a) Taping Dimension

(unit: mm)

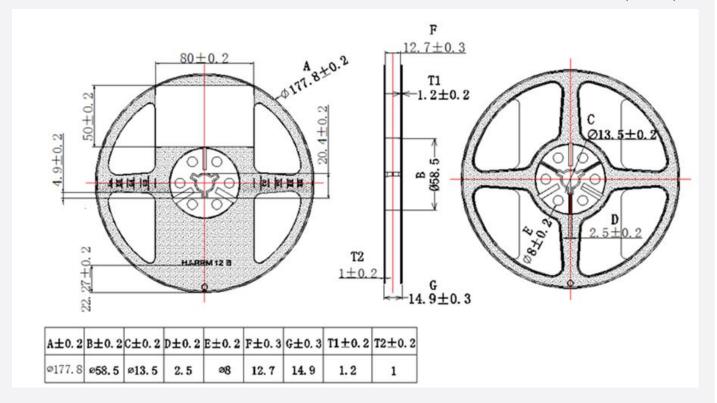
I.	TEM	W	A0	В0	KO	Е	F	D0	D1	P0	P1	P2	T		
D	MIC	12.00	5.40	5. 20	0.95	1.75	5. 50	1.50	1.50	4.00	4.00	2.00	0.20	LENGTH	PCS/REEL
5.	. 35	+0. 10 -0. 10	+0. 05 -0. 05	+0. 05 -0. 05	+0. 05 -0. 05	+0. 10 -0. 10	+0. 10 -0. 10	+0. 10 -0. 00	+0. 10 -0. 00	+0. 10 0. 00	+0. 10 -0. 10	+0. 10 -0. 10	+0. 05 -0. 05	m	PCS





## b) Reel Dimension (max 2,000 pcs)

(unit: mm)

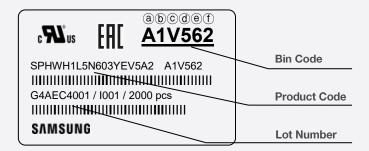


## Notes:

- 1) Quantity: The quantity/reel is 2000 pcs
- 2) All dimensions are millimeters.
- 3) Packaging: P/N, Manufacturing data code no. and quantity are indicated on the aluminum packing bag.

### 8. Label Structure

### a) Label Structure



Note: Denoted bin code and product code above is only an example (see description on page 5)

Bin Code:

(a) (b): Forward Voltage bin (refer to page 7)(c) (d): Chromaticity bin (refer to page 8)(e) (f): Luminous Flux bin (refer to page 6)

## b) Lot Number

The lot number is composed of the following characters:



SAMSUNG

## 123456789/Iabc / xxxx pcs

① ② : Production site (G4 : Guangzhou ,China)

: Product state (A: Normal, B: Bulk, C: First Production, R: Reproduction, S: Sample)

(D:2019, E:2020, F:2021 ... )

(5) : Month (1-9, A, B, C)(6) : Day (1-9, A, B-V)

(001 - 999) : Samsung Electronics Product serial number

(a) (b) (c) : Reel number(001 - 999)

## 9. Packing Structure a) Packing Process Reel Reel .**91**≈ [∏[ <u>A1V562</u> [f][ A1V562 SPHWH1L5N603YEV5A2 A1V562 G4AEC4001 / I001 / 2000 pcs SAMSUNG **Desiccant Humidity indicator** 000,000 **Aluminum Vinyl Packing Bag** A1V562 SPHWH1L5N603YEV5A2 A1V562 0 2a **₽1** us [∏[ <u>A1V562</u> G4AEC4001 / I001 / 2000 pcs SAMSUNG **Outer Box** Material: Paper (SW3B(B)) Size (mm) Note Type W L Н 7 inch S 245 ± 5 220 ± 5 $86 \pm 5$ Up to 5 reels 7 inch L 245 ± 5 220 ± 5 182 ± 5 Up to 10 reels Side Label [F][ A1V562 SAMSUNG Side Label SPHWH1L5N603YEV5A2 A1V562 Н G4AEC4001 / I001 / 2000 pcs **LED** SAMSUNG Paper(SW3B(B))

#### b) Aluminum Vinyl Packing Bag



## CAUTION

# LEVEL

## This bag contains MOISTURE SENSITIVE DEVICES

- 1. Shelf life in sealed bag: 12 months at < 40°C and < 90% relative humidity (RH)
- 2. Peak package body temperature: 240 °C
- 3. After this bag is opened, devices that will be subjected to reflow soldor or other high temperature processes must be:
  - a. Mounted within 672 hours at factory conditions of equal to or less than 30°C /60% RH, or
  - h Stored at < 10% RH
- 4. Devices require bake, before mounting, if:
  - a. Humidity Indicator Card is > 60% when read at 23±5°C, or b. 2a is not met.
- 5. If baking is required, devices must be baked for 10 24 hours at 60 ± 5°C Note: if device containers cannot be subjected to high temperature or shorter bake times are desired, reference IPC/JEDEC J-STD-033 for bake procedure.

Bag seal due date: .

(I blank, see code label)

Note: Level and body temperature by IPC/JEDEC J-STD-020

# c**FL**us [F][ <u>A1V562</u>

SPHWH1L5N603YEV5A2 A1V562 G4AEC4001 / I001 / 2000 pcs SAMSUNG









## ■ 주의 사항

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### ■ Important

This Al Zipper bag is designed to protect the enclosed products from moisture and ESD. Once opened, the products should be soldered onto the printed circuit board immediately. When not in use, please do not leave the products unprotected by the Al Zipper Bag. To repack unused products., please ensure the zip-lock is completely sealed with the dry pack left inside.

c) Silica Gel & Humidity Indicator Card inside Aluminum Vinyl Bag

(This image is for reference only. Silicagel and humidity indicator shapes may be different.)





## 10. Precautions in Handling & Use

- 1) For over-current protection, users are recommended to apply resistors connected in series with the LEDs to mitigate sudden change of the forward current caused by shift of forward voltage.
- 2) This device should not be used in any type of fluid such as water, oil, organic solvent, etc. When cleaning is required, IPA is recommended as the cleaning agent. Some solvent-based cleaning agent may damage the silicone resins used in the device.
- 3) When the device is in operation, the forward current should be carefully determined considering the maximum ambient temperature and corresponding junction temperature.
- 4) LEDs must be stored in a clean environment. Shelf life of sealed bags is 12 months at temperature 0~40℃, 0~90 % RH.
- 5) After storage bag is opened, device subjected to soldering, solder reflow, or other high temperature processes must be:
  - a. Mounted within 672 hours (28 days) at an assembly line with a condition of no more than 30° / 60 % RH, or
  - b. Stored at <10 % RH
- 6) Repack unused devices with anti-moisture packing, fold to close any opening and then store in a dry place.
- 7) Devices require baking before mounting, if humidity card reading is >60 % at 23  $\pm$  5  $^{\circ}$ C
- 8) Devices must be baked for 1 hour at  $60 \pm 5^{\circ}$ C, if baking is required.
- 9) The LEDs are sensitive to the static electricity and surge current. It is recommended to use a wrist band or anti-electrostatic glove when handling the LEDs. If voltage exceeding the absolute maximum rating is applied to LEDs, it may cause damage or even destruction to LED devices. Damaged LEDs may show some unusual characteristics such as increase in leakage current, lowered turn-on voltage, or abnormal lighting of LEDs at low current.
- 10) VOCs (Volatile Organic Compounds) can be generated from adhesives, flux, hardener or organic additives used in luminaires (fixtures). Transparent LED silicone encapsulant is permeable to those chemicals and they may lead to a discoloration of encapsulant when they exposed to heat or light. This phenomenon can cause a significant loss of light emitted (output) from the luminaires. In order to prevent these problems, we recommend users to know the physical properties of materials used in luminaires and they must be carefully selected.
- 11) Risk of sulfurization (or tarnishing)
  - The LED from Samsung Electronics Co., Ltd. uses a silver-plated lead frame and its surface color may change to black (or dark colored) when it is exposed to sulfur (S), chlorine (Cl) or other halogen compound. Sulfurization of lead frame may cause intensity degradation, change of chromaticity coordinates and, in extreme cases, open circuit. It requires caution. Due to possible sulfurization of lead frame, LED should not be used and stored together with oxidizing substances made of materials such as: rubber, plain paper, lead solder cream, etc.



# Legal and additional information.

#### About Samsung Electronics Co., Ltd.

Samsung Electronics Co., Ltd. inspires the world and shapes the future with transformative ideas and technologies, redefining the worlds of TVs, smartphones, wearable devices, tablets, cameras, digital appliances, printers, medical equipment, network systems and semiconductors.

We are also leading in the Internet of Things space through, among others, our Digital Health and Smart Home initiatives. We employ 307,000 people across 84 countries. To discover more, please visit our official website at www.samsung.com and our official blog at global.samsungtomorrow.com.

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